

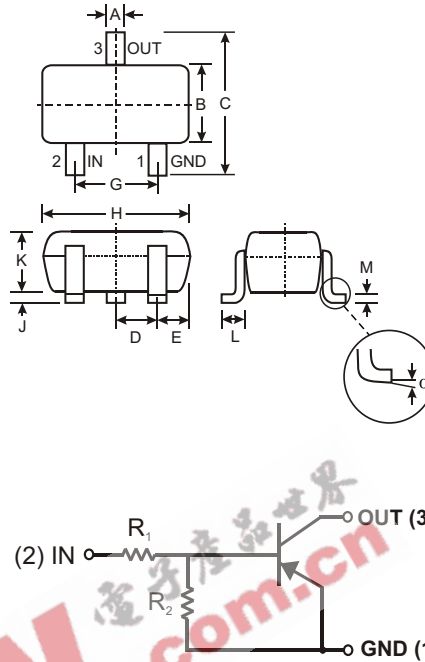
Features

- Epitaxial Planar Die Construction
- Complementary NPN Types Available (DDTD)
- Built-In Biasing Resistors
- Lead Free Product

Mechanical Data

- Case: SOT-323, Molded Plastic
- Case material - UL Flammability Rating 94V-0
- Moisture sensitivity: Level 1 per J-STD-020A
- Terminals: Finish - Matte Tin (Note 1)
Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Marking: Date Code and Marking Code (See Diagrams & Page 2)
- Weight: 0.006 grams (approx.)
- Ordering Information (See Page 2)

P/N	R1 (NOM)	R2 (NOM)	MARKING
DDTB122LU	0.22K Ω	10K Ω	P75
DDTB142JU	0.47K Ω	10K Ω	P76
DDTB122TU	0.22K Ω	OPEN	P77
DDTB142TU	0.47K Ω	OPEN	P78



SOT-323		
Dim	Min	Max
A	0.25	0.40
B	1.15	1.35
C	2.00	2.20
D	0.65 Nominal	
E	0.30	0.40
G	1.20	1.40
H	1.80	2.20
J	0.0	0.10
K	0.90	1.00
L	0.25	0.40
M	0.10	0.18
α	0°	8°
All Dimensions in mm		

Maximum Ratings @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Supply Voltage, (3) to (1)	V _{CC}	-50	V
Input Voltage, (2) to (1)	V _{IN}	+5 to -6 +5 to -6	V
Input Voltage, (1) to (2)	V _{EBO (MAX)}	-5	V
Output Current	I _C	-500	mA
Power Dissipation (Note 2)	P _d	200	mW
Thermal Resistance, Junction to Ambient Air (Note 2)	R _{θJA}	625	°C/W
Operating and Storage and Temperature Range	T _j , T _{STG}	-55 to +150	°C

- Note: 1. If lead-bearing terminal plating is required, please contact your Diodes Inc. sales representative for availability and minimum order details.
2. Mounted on FR4 PC Board with recommended pad layout at <http://www.diodes.com/datasheets/ap02001.pdf>.

Electrical Characteristics @ T_A = 25°C unless otherwise specified

R1, R2 Types

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition	
Input Voltage	DDTB122LU DDTB142JU	V _{I(off)}	-0.3 -0.3	—	—	V	V _{CC} = -5V, I _O = -100μA
	DDTB122LU DDTB142JU	V _{I(on)}	—	—	-2.0 -2.0	V	V _O = -0.3V, I _O = -20mA V _O = -0.3V, I _O = -20mA
Output Voltage		V _{O(on)}	—	—	-0.3V	V	I _O /I _I = -50mA/-2.5mA
Input Current	DDTB122LU DDTB142JU	I _I	—	—	-28 -13	mA	V _I = -5V
Output Current		I _{O(off)}	—	—	-0.5	μA	V _{CC} = -50V, V _I = 0V
DC Current Gain	DDTB122LU DDTB142JU	G _I	56 56	—	—	—	V _O = -5V, I _O = -50mA
Gain-Bandwidth Product*		f _T	—	200	—	MHz	V _{CE} = -10V, I _E = -5mA, f = 100MHz

* Transistor - For Reference Only

Electrical Characteristics @ T_A = 25°C unless otherwise specified

R1-Only Types

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition	
Collector-Base Breakdown Voltage	BV _{CBO}	-50	—	—	V	I _C = -50μA	
Collector-Emitter Breakdown Voltage	BV _{CEO}	-40	—	—	V	I _C = -1mA	
Emitter-Base Breakdown Voltage	DDTB122TU DDTB142TU	BV _{EBO}	-5	—	—	V	I _E = -50μA I _E = -50μA
Collector Cutoff Current	I _{CBO}	—	—	-0.5	μA	V _{CB} = -50V	
Emitter Cutoff Current	DDTB122TU DDTB142TU	I _{EBO}	—	—	-0.5 -0.5	μA	V _{EB} = -4V
Collector-Emitter Saturation Voltage	V _{CE(sat)}	—	—	-0.3	V	I _C = -50mA, I _B = -2.5mA	
DC Current Transfer Ratio	DDTB122TU DDTB142TU	h _{FE}	100 100	250 250	600 600	—	I _C = -5mA, V _{CE} = -5V
Gain-Bandwidth Product*		f _T	—	200	—	MHz	V _{CE} = -10V, I _E = 5mA, f = 100MHz

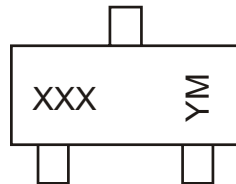
* Transistor - For Reference Only

Ordering Information (Note 3)

Device	Packaging	Shipping
DDTB122LU-7	SOT-323	3000/Tape & Reel
DDTB142JU-7	SOT-323	3000/Tape & Reel
DDTB122TU-7	SOT-323	3000/Tape & Reel
DDTB142TU-7	SOT-323	3000/Tape & Reel

- Notes: 1. If lead-bearing terminal plating is required, please contact your Diodes Inc. sales representative for availability and minimum order details.
3. For Packaging Details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

Marking Information



XXX = Product Type Marking Code
See Sheet 1 Diagrams
YM = Date Code Marking
Y = Year ex: P = 2003
M = Month ex: 9 = September

Date Code Key

Year	2002	2003	2004	2005	2006	2007	2008	2009
Code	N	P	R	S	T	U	V	W

Month	Jan	Feb	March	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

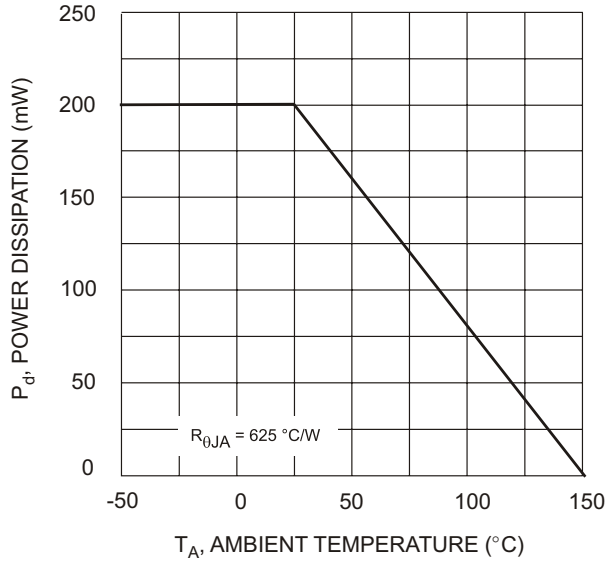


Fig. 1 Power Derating Curve

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